XR-1015/1016 Seventh Order Elliptic

Low Pass Filters

September 1996-4

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FEATURES

• Greater than 70 dB Stopband Rejection

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- Operation at +5 VDC
- Precise Filter Positioning
- Low Power Consumption
- No External Components Required for Filter

APPLICATIONS

- General Purpose Filtering
- Anti-alias Filters (for analog-to-digital converters)
- Reconstruction Filters (for digital-to-analog converters)
- Band Limiting of Voice
- Digital Signal Processing Front End
- Filtering of Voice for Music for Special Effects (echo, phasing, etc.)

GENERAL DESCRIPTION

The XR-1015 and XR-1016 are seven pole and six zero elliptic low pass switched capacitor filters. The position of the passband of the filter is set by the frequency of the clock which allows for easy adjustment. The use of switched capacitor filters reduces the amount of variation in the filter response that occurs with discrete use of capacitors, inductors and resistors. The XR-1015 and XR-1016 also provide synchronized sampled inputs and outputs that allows the device to be cascaded without the need of an additional sample-and-hold. The XR-1015 and XR-1016 are produced with a 3 μ m polysilicon gate dual metal CMOS process for low power consumption.

The XR-1015 is an eight pin device that can operate from +3, -2.0 VDC to \pm 5VDC. The device can also be biased

so that it can be operated with a single +5 to +10 VDC supply. It is pin-for-pin compatible with the Reticon R5609 with the added advantage of operating to +5 VDC single supply. The clock to corner ratio of the XR-1015 is fixed at 100:1.

The XR-1016 is a 14 pin device which provides two uncommitted operational amplifiers for use as a reconstruction filter, anti-aliasing filters or for additional pre-filter gain. The XR-1016, as does the XR-1015, provides a clock output with the voltage output from rail to rail. The XR-1016 has the ability to change the clock to corner ratio from 100:1 to 50:1. The output clock can be used to strobe an analog-to-digital converter or to synchronize any additional circuits in the system.

ORDERING INFORMATION

Rev. 1.01

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Part No.	Package	Operating Temperature Range
XR-1015CN	8 Lead 300 Mil CDIP	0°C to 70°C
XR-1015CP	8 Lead 300 Mil PDIP	0°C to 70°C
XR-1016CN	14 Lead 300 Mil CDIP	0°C to 70°C
XR-1016CP	14 Lead 300 Mil PDIP	0°C to 70°C
XR-1016CD	16 Lead 300 Mil JEDEC SOIC	0°C to 70°C





BLOCK DIAGRAM



Figure 1. XR-1015 Block Diagram





PIN CONFIGURATION



PIN DESCRIPTION

1015 Pin #	1016 Pin #	Symbol	Description					
1	1	5/10	This controls the reference level of the internal level shifters of the XR-1015 or XR-1016 in order to determine the point at which the device considers the digital inputs to be a logic 1 or a logic 0. When this input is at V_{SS} , the decision level is at 2/3 of the sum of the magnitudes of the V_{DD} and V_{SS} levels relative to V_{SS} . When the 5/10 pin is tied high, then the decision level is set for 2/3 of the sum of the magnitudes of the V_{DD} and V_{SS} in voltage relative to V_{DD} . Table 1 shows some of the possibilities of the input logic thresholds.					
			The level at pin 1 does not V_{DD} to near V_{SS} in amplitude	affect the clock output	t amplitude. This output is always from near			
			V _{DD} /V _{SS}	Level at Pin 1	Logic Decision Level			
			+5/-5 VDC	-5 VDC +5	1.8 VDC -1.8 VDC			
			+5/0 VDC	0 +5	3.7 VDC 1.8 VDC			
			+2.5/-2.5 VDC	-2.5	1.2 VDC			
			+10/0 VDC	+2.5	-0.7 VDC 6.8 VDC			
				+10	3.2 VDC			
			Table 1.					
2	2	OUTPUT	The filter output. This output voltage set by ANALOG RE	it will drive a 10kΩ loa EFERENCE.	d. The signal will be centered around the			
3	-	CLOCKIN	The input clock is applied a quency of the filter using th	t this point. The input e ratio:	clock controls the position of the corner fre-			
			$\frac{f_{CLOCK}}{f_{COMER}} = 100:1$					
			The logic threshold level ne description of 5/10 for detail	The logic threshold level needed at this point is controlled by pin 1, 5/10. Please see the pin description of 5/10 for details.				
-	3	CLOCKIN	The input clock is applied to either a clock to corner ratio CLOCKIN is low, fclock/fco	o this point. The XR-1 o of 100:1 or 50:1. Thi rner = 100:1.	016 has an internal divider which provides is controlled by pin 8 (CLOCK SELECT). If			





PIN DESCRIPTION (CONT'D)

1015 Pin #	1016 Pin #	Symbol	Description
4	4	CLOCK/2	This output is the same frequency as the sampling frequency of the XR-1015 or XR-1016. It can be used to synchronize an analog-to-digital converter to the filter's output. The failing edge of the CLOCK/2 output is the edge which the output (pin 2) should be sampled in order to ensure that the output has settled.
-	5	A (OUT)	Operational amplifier A output. This is provided for creating additional filtering if desired. This output can drive a load of typically $10k\Omega$.
-	6	A (-INPUT)	Operational amplifier A negative input. This is a CMOS gate input with virtually infinite input impedance.
-	7	A (+INPUT)	Operational amplifier A positive input. This is a CMOS gate input with virtually infinite input impedance.
-	8	CLOCK SELECT	This pin on the XR-1016 will select the clock to corner ratio of the filter. When this pin is at logic 0, the filter will have a clock to corner of 100:1. When this pin is tied to a logic 1, the clock to corner ratio will be 50:1. The CLOCK/CLOCK \div 2 will always represent the sampling frequency of the XR-1016. The logic level control of this digital input is controlled by pin 1 5/10 as described under that pin description.
-	9	B (-INPUT)	Operational amplifier B negative input. Notice that the positive input of this operational amplifier 8 is tied internally to the ANALOG REFERENCE.
-	10	B (OUT)	Operational amplifier B output.
5	11	V _{DD}	Positive supply input. The range of voltages of this point is from +2.5 VDC to +5 VDC when used with dual supplies of equal magnitude. If a single supply is used, the range is from +5 VDC to +10 VDC. It is recommended that a 0.47 μ F capacitor be tied from this pin to ground to decouple the noise on the supply line which can degrade the performance of the filter. If very low clock frequencies are used, then the size of the capacitor should be increased to keep the noise on the supply at a minimum. This capacitor should be located as close to the V _{DD} pin as possible. It is suggested that a 10 Ω resistor from the positive supply to V _{DD} be used to filter system supply noise from the filter.
6	12	V _{SS}	Negative supply input. The range of the input is from -5 VDC to 0 VDC depending on the voltage present at V _{DD} . It is recommended that the pin be decoupled with a 0.47µF capacitor located as physically close as possible to the V _{SS} pin and tied from V _{SS} to ground. It is recommended that a 10 Ω resistor from the negative supply to V _{SS} be used to filter system supply noise from the filter.
7	13	ANALOG REF.	This pin provides the level at which the analog signals will be referenced. If equal split supplies are used, then this point is tied to ground. If unequal supplies or a single supply is used, then this point should be tied to a resistor divider circuit to provide a voltage at the analog reference pin that is 1/2 of the algebraic sum of the two supplies. Since this point is used as analog ground inside the device, it is recommended that a 0.47μ F capacitor be tied from this pin to ground. As with the V _{DD} and V _{SS} decoupling, the size of this capacitor should be made larger if the clock frequency is decreased.
8	14	FILTER IN	Filter input: The signal that needs to be filtered is applied to this point. It has an input imped- ance of $4M\Omega$ at 1MHz clock frequency. It should be noted that any signal applied to this input greater than 1/2 of the sampling frequency will be aliased into the band of interest.





ELECTRICAL CHARACTERISTICS

Test Conditions: V+ = 5 VDC, V- = -5 VDC, f_{CLOCK} = 2MHz, R_L = 1 M Ω , C_L = 40pF, T_A = 25°C Unless Otherwise Specified.

			XR-1015		XR-1016				
Symbol	Parameters	Min.	Тур.	Max.	Min.	Тур.	Max.	Units	Conditions
General Cha	racteristics		•						
	Supply Voltage								
	Single Supply	5		10.5				V	See Figure 2.
					5		10.5	V	See Figure 4.
	Split Supply	+3, -2		15.25				V	See Figure 3.
					+3, -2		\pm 5.25	V	See Figure 5.
	Supply Current								
	Single Supply		10	11				mA	See Figure 2.
						10	11	mA	See Figure 4.
	Split Supply								
	Positive		10	12				mA	See Figure 3.
	Negative		10	12				mA	
	Positive					10	12	mA	See Figure 5.
	Negative					10	12	mA	
Filter Section	n	-							
fclock	Upper Frequency Limit	2	2.5					MHz	See Figure 3.
					2	2.5		MHz	See Figure 5.
f _{CLOCKMIN}	Lowest Practical		1					kHz	See Figure 3.
							1	kHz	See Figure 5.
	Input Impedance								
	Pin 8		1					mΩ	See <i>Figure 3.</i> , f _{CLOCK} = 1MHz
	Pin 14					1			See <i>Figure 5.</i> f _{CLOCK} = 1MHz
tpw	Minimum f _{CLOCK} Pulse Width	200						ns	See Figure 3.
					200			ns	See Figure 5.
THD	Total Harmonic Distortion								$V_{IN} = 2 Vpp$
			0.02%			0.02%			f _{CLOCK} = 500kHz
			0.1%			0.1%			f _{CLOCK} = 2MHz
	Clock Feedthrough		30			30		mVpp	
V _{INMAX}	Maximum Input Voltage			8			8	Vpp	Above which distortion increases.
	Corner Freq. Accuracy		±0.5	±1		±0.5	±1	%	f _{CLOCK} = 2MHz



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ELECTRICAL CHARACTERISTICS (CONT'D)

			XR-1015			XR-1016			
Symbol	Parameters	Min.	Тур.	Max.	Min.	Тур.	Max.	Units	Conditions
A _V	Passband Gain	-0.5	0	+0.5	-0.5	0	+0.5	dB	Tested at f _{IN} = 293Hz, 3.9kHz, 8.6kHz, 12.1kHz
		-1	0	+1	-1	0	+1	dB	Tested at f _{IN} = 15.3kHz, 17.1kHz
	Ripple Passband		±0.1			±0.1		dB	f _{CLOCK} = 500kHz
			±0.5	1		± 0.5	1	dB	f _{CLOCK} = 2MHz
V _{OS}	Voltage Offset	-0.5	-0.2	+0.5	-0.5	-0.2	+0.5	VDC	
	Output Noise		0.6			0.6		mVrms	1Hz-20Hz, Figure 9.
Operation A	mplifier	•	•				•		
	Unity Gain Bandwidth		1.2			1.2		MHz	
CMRR	Common Mode Rejection Ratio (2 Vpp Input)		50			50		dB	
V _{IO}	Input Offset Voltage	-30		30	-30		30	mV	

Specifications are subject to change without notice

ABSOLUTE MAXIMUM RATINGS

Power Supply	14V
Input Signal Level V+ +	0.3 to V- \pm 0.3V
Power Dissipation - XR-1016 (Packag	e Limitation)
Ceramic Package	1000mW
Derate Above $T_A = +25^{\circ}C$	6mW/°C
Plastic Package	800mW

Derate Above $T_A = +25^{\circ}C$.	7mW/°C
Power Dissipation - XR-1015	
Ceramic Package	385mW
Derate Above $T_A = +25^{\circ}C$.	8.3mW/°C
Plastic Package	300mW
Derate Above $T_A = +25^{\circ}C$	8.3mW/°C
Storage Temperature	-55°C to +150°C





SYSTEM DESCRIPTION

The XR-1015 and XR-1016 General Purpose Seventh Order Elliptic Switched Capacitor Low Pass Filters are usually used as the first or last stage in any sampled signal system.

Any signal from the -3dB point of the low pass response to 1/2 of the sampling frequency (1/4 of the clock frequency) will be attenuated by typically 75dB, referenced to the passband. This allows its use with analog-to-digital converters to prevent the A-to-D from aliasing signals that are above 1/2 of the sampling frequency of the analog-to-digital converter. A simple second order active filter can be used in front of the XR-1015 or XR-1016 if it is known that some input signals will be above the Nyquist frequency of the XR-1015 or XR-1016.

The reverse of the above circuit can be used for digital-to-analog converters, to prevent the sampling frequency from causing difficulties with other stages in the system.

Application Information

The XR-1015 and XR-1016 are fabricated in P-well CMOS. This uses a N-substrate and requires the V_{DD} to be applied first before V_{SS} in order to prevent latchup of the device.

In addition to the above caution, the input signals should not be applied above the power supply levels, to prevent latchup. The same is true of the input clock.

The input signal should not have any traces or wires near the clock or other system clocks. The same is true of the output. This will help to reduce the clock feedthrough and provide measurements equal to the datasheet values, or better.

PRINCIPLES OF OPERATION

The XR-1015 and XR-1016 are switched capacitor filters with seven poles and six zeros with an elliptic response.

With the elliptic response of the filter, the stop band rejection is greater than 75dB. The elliptic filter response is called an equal-ripple response, where the ripple in the stop band is an approximation of the ripple in the pass band. In this way the rolloff of the filter response is very fast as shown in *Figure 6*.

The use of zeros to obtain the stop band attenuation does cause some change in the linearity of the group delay of the elliptic filter. The rapid change in group delay occurs near the corner frequency as shown in *Figure 7*. This would only be a factor in situations where the output signal must not be delayed by different times for different input frequencies. For applications where the distortion of the phase information is important, the corner frequency of the filter can be placed higher in frequency so that the linear portion of the group delay response of the filter can be located within the information band.

Since the XR-1015 and XR-1016 are sample data filters in that they divide the continuous time signal into an amount of charge at a given time, certain limitations must be made on the signals placed on the input of the filters. The frequency of the signal applied to this input must have a period so that at least two samples of the signal are made during the period of the signal. This is true even if the signal is in the stop band response of the filter. The reason for this is that it would take a minimum of two samples of the frequency being applied to establish the period of the signal as well as an approximation of the amplitude. If this sampling criteria is not followed, then the output of the filter will be an aliased signal of the input since the period of the signal would be not accurately known and the frequency would not be known.

If this situation may occur, a simple second order filter can be added to the input. With the XR-1016, operational amplifier A could be used to create this filter. The precision of the location of the corner frequency of the filter is not critical in this situation so that precision resistors and capacitors would not be needed.





Figure 2. XR-1015 Test Circuit: 5 V Operation (V_{DD} = +5 V, V_{SS} = 0 V, Ref = +2 V)



Figure 3. XR-1015 Test Circuit: 10 V Operation (V_{DD} = +5 V, V_{SS} = -5 V)







Figure 4. XR-1016 Test Circuit: 5 V Operation (V_{DD} = +5 V, V_{SS} = 0 V, Ref = +2 V)



Figure 5. XR-1016 Test Circuit: 10 V Operation (V_{DD} = +5 V, V_{SS} = -5VDC)











Figure 7. Group Delay Response







Figure 8. Typical Passband Ripple



Figure 9. Typical Output Noise















8 LEAD PLASTIC DUAL-IN-LINE (300 MIL PDIP)

Rev. 1.00



	INC	HES	MILLIN	IETERS
SYMBOL	MIN	MAX	MIN	MAX
А	0.145	0.210	3.68	5.33
A ₁	0.015	0.070	0.38	1.78
A ₂	0.015	0.195	2.92	4.95
В	0.014	0.024	0.36	0.56
B ₁	0.030	0.070	0.76	1.78
С	0.008	0.014	0.20	0.38
D	0.348	0.430	8.84	10.92
Е	0.300	0.325	7.62	8.26
E ₁	0.240	0.280	6.10	7.11
е	0.1	00 BSC	2.5	4 BSC
e _A	0.3	00 BSC	7.6	2 BSC
e _B	0.310	0.430	7.87	10.92
L	0.115	0.160	2.92	4.06
α	0°	15°	0°	15°





8 LEAD CERAMIC DUAL-IN-LINE (300 MIL CDIP)

Rev. 1.00



	INC	HES	MILLIN	IETERS		
SYMBOL	MIN	МАХ	MIN	MAX		
А	0.100	0.200	2.54	5.08		
A ₁	0.015	0.060	0.38	1.52		
В	0.014	0.026	0.36	0.66		
B ₁	0.045	0.065	1.14	1.65		
С	0.008	0.018	0.20	0.46		
D	0.305	0.405	7.75	10.29		
E ₁	0.250	0.310	6.35	7.87		
E	0.3	00 BSC	7.6	2 BSC		
е	0.1	00 BSC	2.5	2.54 BSC		
L	0.125	0.200	3.18	5.08		
α	0°	15°	0°	15°		





14 LEAD PLASTIC DUAL-IN-LINE (300 MIL PDIP)

Rev. 1.00



	INC	HES	MILLIN	IETERS
SYMBOL	MIN	MAX	MIN	MAX
А	0.145	0.210	3.68	5.33
A ₁	0.015	0.070	0.38	1.78
A ₂	0.115	0.195	2.92	4.95
В	0.014	0.024	0.36	0.56
B ₁	0.030	0.070	0.76	1.78
С	0.008	0.014	0.20	0.38
D	0.725	0.795	18.42	20.19
E	0.300	0.325	7.62	8.26
E ₁	0.240	0.280	6.10	7.11
е	0.10	DO BSC	2.5	4 BSC
e _A	0.30	DO BSC	7.6	2 BSC
e _B	0.310	0.430	7.87	10.92
L	0.115	0.160	2.92	4.06
α	0°	15°	0°	15°





14 LEAD CERAMIC DUAL-IN-LINE (300 MIL CDIP)

Rev. 1.00



	INC	HES	MILLIN	IETERS		
SYMBOL	MIN	MAX	MIN	MAX		
А	0.100	0.200	2.54	5.08		
A ₁	0.015	0.060	0.38	1.52		
В	0.014	0.026	0.36	0.66		
B1	0.045	0.065	1.14	1.65		
С	0.008	0.018	0.20	0.46		
D	0.685	0.785	17.40	19.94		
E1	0.250	0.310	6.35	7.87		
E	0.3	00 BSC	7.6	2 BSC		
е	0.1	00 BSC	2.5	2.54 BSC		
L	0.125	0.200	3.18	5.08		
α	0°	15°	0°	15°		





16 LEAD SMALL OUTLINE (300 MIL JEDEC SOIC)

Rev. 1.00



	INC	HES	MILLIN	IETERS
SYMBOL	MIN	MAX	MIN	МАХ
А	0.093	0.104	2.35	2.65
A ₁	0.004	0.012	0.10	0.30
В	0.013	0.020	0.33	0.51
С	0.009	0.013	0.23	0.32
D	0.398	0.413	10.10	10.50
Е	0.291	0.299	7.40	7.60
е	0.0	50 BSC	1.2	7 BSC
н	0.394	0.419	10.00	10.65
L	0.016	0.050	0.40	1.27
α	0°	8°	0°	8°

Note: The control dimension is the millimeter column





Notes





Notes





NOTICE

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